NXP BT152X-600R SCR datasheet

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Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

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1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

2. Features and benefits

- High blocking voltage capability
- High thermal cycling performance
- Isolated mounting base package
- Planar passivated for voltage ruggedness and reliability
- Very high current surge capability

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Table 1. Quie	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	200	A
I _{T(RMS)}	RMS on-state current	half sine wave; $T_h \le 43 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	-	20	A
Static characte	eristics		 		-	-
I _{GT}	gate trigger current	V_D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	3	32	mA





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Pinning information 5.

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	А -Ң -К
2	А	anode		G sym037
3	G	gate		
mb	n.c.	mounting base; isolated		
			TO-220F (SOT186A)	

Ordering information 6.

Table 3. Ordering i	information		
Type number	Package		
	Name	Description	Version
BT152X-600R	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A

Limiting values 7.

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; $T_h \le 43 \text{ °C}$	-	13	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_h \le 43 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	20	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	200	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	220	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	200	A ² s
dI _T /dt	rate of rise of on-state current	I_{T} = 50 A; I_{G} = 0.2 A; dI_{G}/dt = 0.2 A/µs	-	200	A/µs
I _{GM}	peak gate current		-	5	Α

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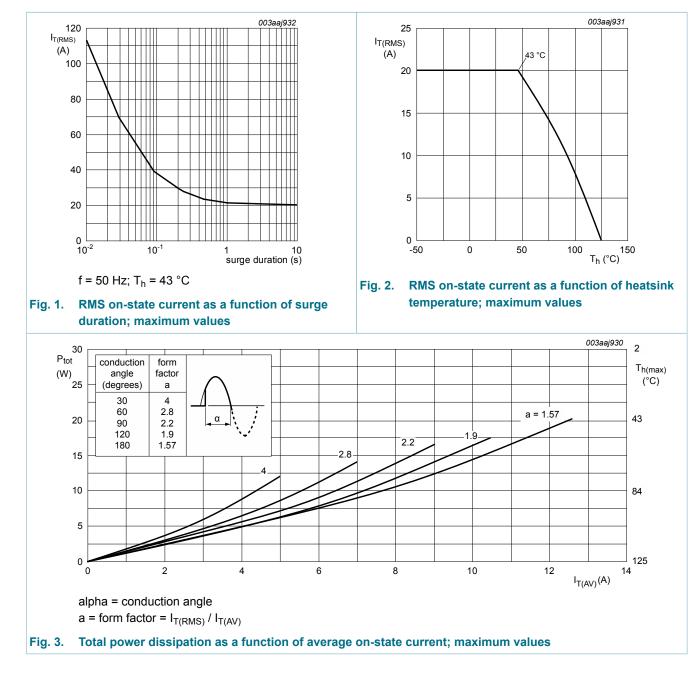
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Symbol	Parameter	Conditions	Min	Max	Unit
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	20	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

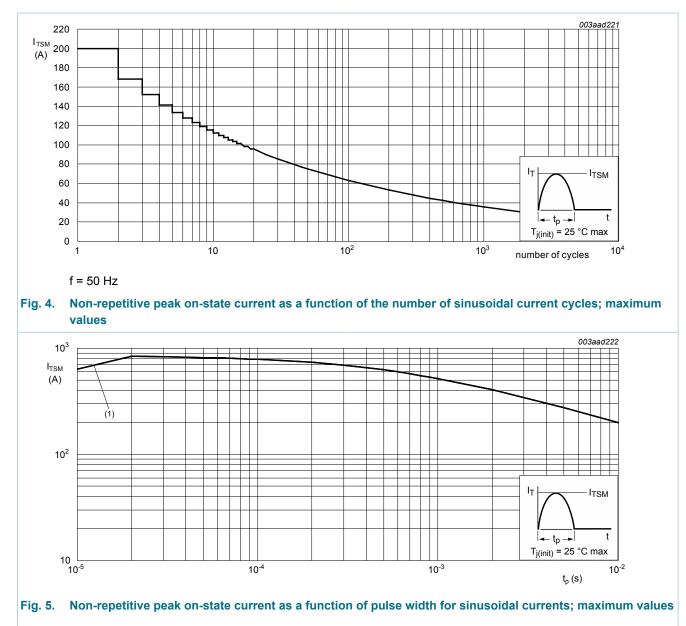


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 $t_{\rm p}~\leq~10~ms;~~(1)~dI_T/dt~limit$

8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance	with heatsink compound; Fig. 6	-	-	4	K/W
	from junction to heatsink	without heatsink compound; Fig. 6	-	-	4.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	55	-	K/W

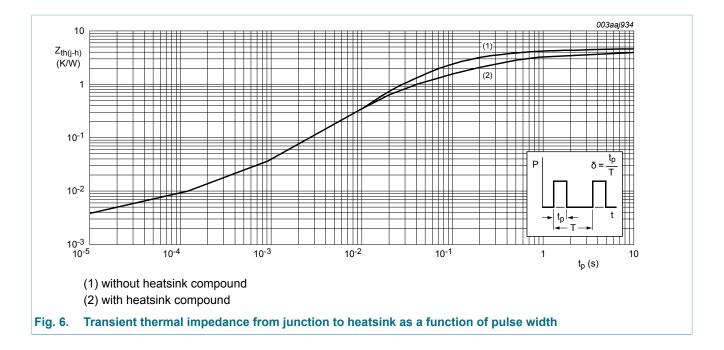
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9. Isolation characteristics

Table 6. Iso	olation characteristics						
Symbol	Parameter	Conditions	I	Min	Тур	Мах	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	-	2500	V
C _{isol}	isolation capacitance	from anode to external heatsink; f = 1 MHz; T _h = 25 °C	-	-	10	-	pF

10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	3	32	mA
۱ _L	latching current	V_D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	25	80	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	15	60	mA
V _T	on-state voltage	I _T = 40 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.6	1	V
		V _D = 600 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11	0.25	0.4	-	V

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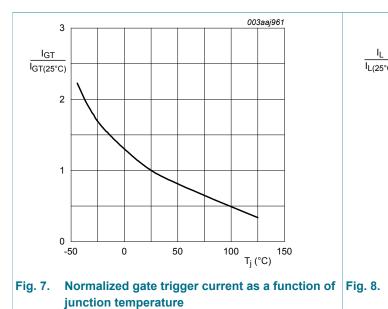
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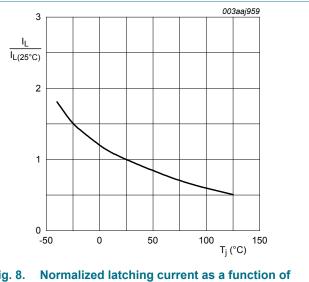
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.2	1	mA
I _R	reverse current	V _R = 600 V; T _j = 125 °C	-	0.2	1	mA
Dynamic char	acteristics	·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); gate open circuit; exponential waveform; Fig. 12	200	300	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 40 A; V _D = 600 V; I _G = 0.1 A; dI _G / dt = 5 A/µs; T _j = 25 °C	-	2	-	μs
tq	commutated turn-off time	$\begin{split} &V_{DM} = 402 \; V; \; T_j = 125 \; ^\circ C; \; I_{TM} = 50 \; A; \\ &V_R = 25 \; V; \; (dI_T/dt)_M = 50 \; A/\mu s; \; dV_D/ \\ &dt = 30 \; V/\mu s; \; R_{GK} = 100 \; \Omega; \; (V_{DM} = 67\% \\ &of \; V_{DRM}) \end{split}$	-	70	-	μs





junction temperature

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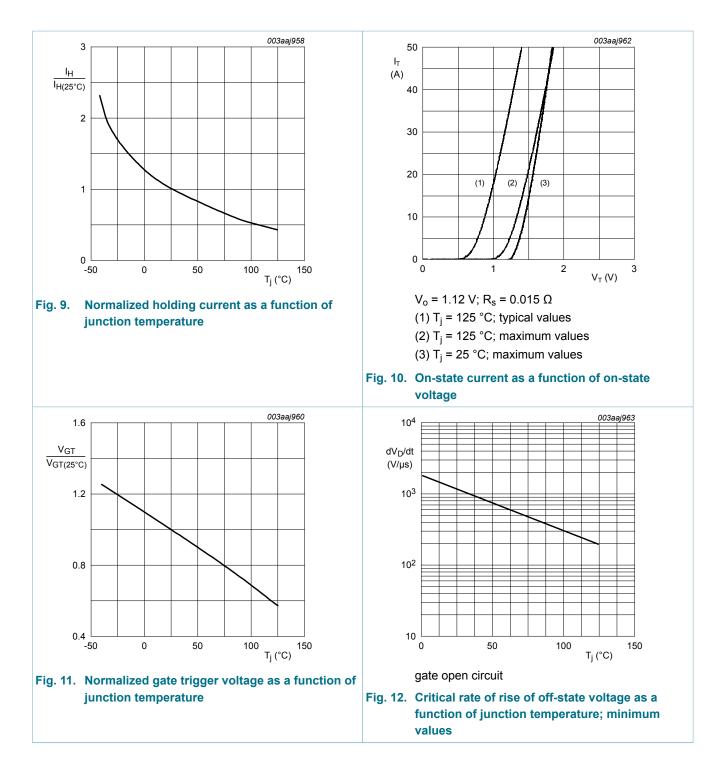
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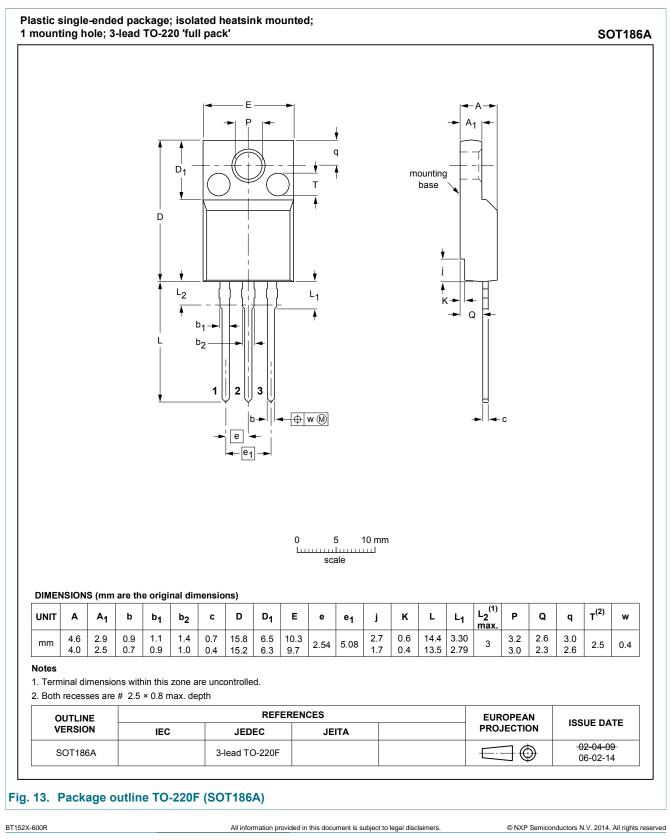
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11. Package outline



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12. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
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